## **RSC** Advances



View Article Online

View Journal | View Issue

## PAPER

Check for updates

Cite this: RSC Adv., 2021, 11, 39672

Received 26th October 2021 Accepted 7th December 2021

DOI: 10.1039/d1ra07876c

rsc.li/rsc-advances

## 1 Introduction

Two-dimensional (2D) layered-nanomaterials along with graphene<sup>1</sup> are strongly investigated both theoretically and experimentally<sup>2-6</sup> due to their outstanding properties which meet the demands of future applications. The large-scale research turned to search alternate 2D materials including graphene-like structures when shortcomings of graphene emerged. Consequently, a series of 2D nanomaterials have been reported, such as phosphorene,<sup>7,8</sup> Xene (stanene,<sup>9</sup> silicene<sup>10</sup> or germanene),<sup>11,12</sup> hexagonal boron nitride (h-BN),<sup>13</sup> transition metal chalcogenides (TMDs)<sup>14,15</sup> and so forth. They possess many superior mechanical, electronic, and photocatalytic properties which do not exist in 2D forms.<sup>16-20</sup> Among the 2D materials mentioned above, the layered TMDs have attracted considerable interest due to their unique structure, extraordinary physical properties,

# First-principles insights onto structural, electronic and optical properties of Janus monolayers CrXO (X = S, Se, Te)

Tran P. T. Linh,<sup>a</sup> Nguyen N. Hieu, <sup>b</sup>\*<sup>bc</sup> Huynh V. Phuc,<sup>d</sup> Cuong Q. Nguyen, <sup>b</sup><sup>bc</sup> Pham T. Vinh,<sup>d</sup> Nguyen Q. Thai<sup>d</sup> and Nguyen V. Hieu<sup>\*e</sup>

The lacking of the vertical mirror symmetry in Janus structures compared to their conventional metal monochalcogenides/dichalcogenides leads to their characteristic properties, which are predicted to play significant roles for various promising applications. In this framework, we systematically examine the structural, mechanical, electronic, and optical properties of the two-dimensional 2H Janus CrXO (X = S, Se, Te) monolayers by using first-principles calculation method based on density functional theory. The obtained results from optimization, phonon spectra, and elastic constants demonstrate that all three Janus monolayers present good structural and mechanical stabilities. The calculated elastic constants also indicate that the Janus CrTeO monolayer is much mechanically flexible than the other two monolayers due to its low Young's modulus value. The metallic behavior is observed at the ground state for the Janus CrSeO and CrTeO monolayers in both PBE and HSE06 levels. Meanwhile, the Janus CrSO monolayer exhibits a low indirect semiconducting characteristic. The bandgap of CrSO after the correction of HSE06 hybrid functional is the average value of its binary transition metal dichalcogenides. The broad absorption spectrum of CrSO reveals the wide activated range from the visible to nearultraviolet region. Our findings not only present insight into the brand-new Janus CrXO monolayers but can also motivate experimental research for several applications in optoelectric and nanoelectromechanical devices.

> and the wide potential applications such as catalysis,<sup>21</sup> optoelectronics and spintronics,<sup>22</sup> electrochemical energy storage,<sup>23</sup> nanoelectronics.<sup>24</sup> Although, there are several significant successes and unprecedented efforts which consequence upon various beyond-graphene 2D systems, the complete potentials of such systems are still unexplored which may restrict their usage in devices.

> Recently, Janus 2D materials have been considerably interested in as a brand-new class of 2D layered-nanomaterials.<sup>25-29</sup> Owing to the lacking of the vertical symmetry, Janus materials possess asymmetric structures resulting in many new electronic and photocatalytic properties with considerable promising applications such as in energy storage and nanoelectronic technologies.<sup>30-32</sup> The Janus 2D material reported originally in 2009,<sup>33</sup> named graphone, was a graphene-based material obtained by hydrogenating only one side of graphene. Since then, many experimental and theoretical studies have released diverse Janus structures dominantly based on their binary or ternary TMDs.34,35 Therefore, this work is carried out with motivation to firstly simulate the 2D Janus CrXO (X = S, Se, Te) monolayers that can be built from commonly reported transition metal dichalcogenides or oxide CrX<sub>2</sub> or CrO<sub>2</sub>. The TMD monolayers possess the rich chemical diversity and multiple phases of crystalline structures such as octahedral (1T),

<sup>&</sup>lt;sup>a</sup>Faculty of Physics, Hanoi National University of Education, Ha Noi 100000, Viet Nam <sup>b</sup>Institute of Research and Development, Duy Tan University, Da Nang 550000, Viet Nam. E-mail: hieunn@duytan.edu.vn

Faculty of Natural Sciences, Duy Tan University, Da Nang 550000, Viet Nam

<sup>&</sup>lt;sup>d</sup>Division of Theoretical Physics, Dong Thap University, Cao Lanh 870000, Viet Nam <sup>e</sup>Physics Department, The University of Danang – University of Science and Education, Da Nang 550000, Viet Nam. E-mail: nvhieu@ued.udn.vn

#### Paper

hexagonal (2H), and distorted octahedral (1T') structures<sup>36,37</sup> depending on the arrangements of the Cr and chalcogens atoms. Among the three major structures, the semiconducting 2D CrX<sub>2</sub> monolayers with 2H-phases are much interested in due to their more energetically stable forms.38 The 2H-phases of Cr dichalcogenides are direct gap semiconductors, whereas its oxide has an indirect energy gap. Particularly, 2H monolayers CrO<sub>2</sub>, CrS<sub>2</sub>, CrSe<sub>2</sub> and CrTe<sub>2</sub> were previously found to be nonmagnetic materials.<sup>39,40</sup> As for the phonon bandgap, which separates the acoustic vibrational branches from the six optical ones, all of the 2H-phases of Cr dichalcogenides and oxide monolayers are found to be absent resulting in the reduction of thermal conductivity. The 2H-CrO<sub>2</sub> has the largest phonon thermal conductance at all temperatures since it composed of the lightest atoms in the group. Together with the increase in temperature, the thermal conductance of CrO<sub>2</sub> increases significantly.<sup>41</sup> However, the structural symmetry along the outof-plane direction limits the applications of those TMD monolayers. The asymmetric Janus CrXO monolayers not only inherits the advantages of 2H-phases Cr dichalcogenides but also play a key role to control optical and electronic properties which are the crucial deciding factor for various practical applications.

In the present work, by means of first-principles calculation based on DFT, we report the first theoretical investigation on the 2D Janus CrXO monolayers. The current paper is organized as follows: in Section 2, we describe the computational methodologies. Then in Section 3, we discuss the optimized structural parameters and dynamical stability *via* the phonon spectra examination, followed by the discussion of mechanical stability *via* elastic constants survey. The electronic properties are investigated by analyzing the band structures. Since this is the first theoretical and experimental research, our obtained result can provide effective guidance for fabrication, as well as application of the 2D Janus CrXO monolayers in future optoelectronic and nanoelectronic devices.

## 2 Computational methods

All simulations in this study were performed by the DFT method as implemented in the Quantum Espresso code.42 We used the project augmented wave (PAW) method to consider the valence electron-ion core interactions.43 The generalized gradient approximations (GGA) by the Perdew-Burke-Ernzerhof (PBE) were used to treat the correlation and exchange functionals. The spin-orbit coupling (SOC) was taken into account in selfconsistent investigation for electronic characteristics of Janus monolayers.44 Further, the hybrid functional by Heyd-Scuseria-Ernzerhof (HSE06)45 was also used to correct the band structures of the investigated monolayers. The DFT-D2 method by Grimme<sup>46</sup> was also used to correct the van der Waals interactions in the layered materials. The cut-off energy for the planewave basis was adopted as 500 eV. A ( $15 \times 15 \times 1$ ) k-mesh was built by the Monkhorst-Pack method to sample the Brillouin zone. The atomic structures of systems were fully optimized until the residual forces on atoms were less than  $10^{-3}$  eV Å<sup>-1</sup>. We inserted a vertical vacuum space of 20 Å to reduce the interactions between neighbor slabs. Phonon spectra of monolayers were evaluated by the density functional perturbation theory (DFPT) method.<sup>47</sup> The Born–Huang's criteria were used to evaluate the mechanical stability of monolayers.

## 3 Results and discussion

#### 3.1 Geometry and stability

The CrXO (X = S, Se, Te) monolayers can be constructed from CrX<sub>2</sub> or CrO<sub>2</sub>. However, CrO<sub>2</sub> is unstable at room temperature.<sup>48</sup> It is known that CrX<sub>2</sub> stably exists in 2H.<sup>40,49</sup> Hence, the 2H Janus CrXO monolayers can be formed based on 2H CrX<sub>2</sub> by replacing the bottom layer of X with O atoms. The most stable 2H structures (have the lowest energies) of the Janus CrXO (X =S, Se, Te) are optimized and sketched in Fig. 1. It can be seen that Janus CrXO consists of three layers of atoms, namely, X, Cr, and O atoms from the top to the bottom. The optimized inplane hexagonal unit cell lattice constants a of three structures and the vertical distance between the oxygen or chalcogen atoms  $\Delta h$  are listed in Table 1. Both a and  $\Delta h$  values are increasing from CrSO to CrTeO, although the discrepancies are quite small, less than 5%. It is noteworthy that the breaking of the mirror symmetry in the original structure leads to a vertical asymmetry in the Janus CrXO which is evident in the large difference (about 12%) in the bond lengths of Cr–O ( $d_{\rm Cr–O}$ ) and Cr-X ( $d_{\rm Cr-O}$ ). The calculated Cr-O ( $d_{\rm Cr-O}$ ) bond lengths are similar for all three structures, while those of Cr-X  $(d_{Cr-O})$  are quite different, i.e., the shortest one is found for Cr-S (2.26 Å), followed by Cr–Se (2.42 Å), the longest one is found for Cr–Te (2.75 Å). These obtained results can be attributed to the dissimilarity in ionic radii of S (1.84 Å), Se (1.98 Å) and Te (2.21 Å). Note that the free-standing Janus structures may be more stable in the curled forms due to their asymmetry.<sup>50</sup> This observation is consistent with previous predictions that sheets tend to curve in response to



Fig. 1 Different views of optimized atomic structures of Janus CrXO (X = S, Se, Te) monolayers.

Table 1	Calculate the lattice constant a,	bond length $d$ , thickness $\Delta h$	and bond angle $\phi$ of the Janu	s CrXO monolayers (X = S, Se, Te)
---------	-----------------------------------	----------------------------------------	-----------------------------------	-----------------------------------

	a (Å)	$d_{ m Cr-O}( m \AA)$	$d_{\mathrm{Cr-X}}\left(\mathrm{\AA} ight)$	$\Delta h$ (Å)	$\phi_{egin{array}{c} \mathbf{XCrX}} \left( deg  ight)$	$\phi_{ot \operatorname{OCrO}} \left( \operatorname{deg}  ight)$	$\phi_{egin{array}{c}  ext{XCrO}} ( ext{deg})$
CrSO	2.83	1.95	2.26	2.63	77.67	92.85	76.85
CrSeO	2.94	1.96	2.42	2.70	74.55	97.25	75.57
CrTeO	3.09	1.94	2.75	2.86	68.06	105.72	72.74

lattice-mismatch in its structure.<sup>51</sup> In the present study, bending curvature is not included in our calculations.

Next, in order to test the dynamical stability of the Janus CrXO, the phonon dispersion curves along several lines of high symmetry presented in Fig. 2 are analyzed. The frequency and phonon dispersion bands of all three monolayers are not quite different from each other. It is found that these three systems of the Janus CrXO are dynamically stable since there are no imaginary modes in the whole Brillouin zones. As depicted in Fig. 2, the phonon dispersion curves of the Janus CrXO monolayers have 9 vibrational branches, including 3 acoustic branches with low frequencies and 6 optical branches with higher frequencies. There is no gap between optical and acoustic branches resulting in the robust optical-acoustic scattering in CrXO monolayers, and hence, thermal conductivity may be affected. At the  $\Gamma$  point, optical phonons include nondegenerate vibrational modes for CrSO, while for CrSeO and CrTeO, doubly-degenerate vibration modes are found. The reduction in the vibration frequencies and the falling into the lower energy region of the optical branches are found from CrSO to CrTeO. The acoustic bands are also shifted towards low frequencies and specifically are confined in a narrow frequency range. This trend can be attributed to the atomic mass. Since CrSO monolayer has the lowest atomic mass, the vibrational frequencies of CrSO are higher compared to others. The less dispersive acoustic modes, and hence lower group velocity, are observed due to the downward shift of the acoustic branches. Moreover, for the acoustic branches, the lowering of the steepness is the result of weak bonding that is attributed to the increasing Cr-X bond lengths when moving down on a chalcogen atom. This agrees with the previous optimized results.

For more argument of the Janus CrXO monolayers' mechanical strength, which is essential for their applications, elastic constants ( $C_{ij}$ ), Young's modulus ( $Y_{2D}$ ) and Poisson's



Fig. 2 Phonon dispersion curves of the Janus CrXO monolayers.

ratio  $(\nu)$  are examined. Young's modulus is a parameter representing the stiffness of a solid, evaluates the material resistance to elastic (recoverable) deformation under load. The Young's modulus is given by  $Y_{2D} = (C_{11}^2 - C_{12}^2)/C_{11}$ . Poisson's ratio ( $\nu =$  $C_{12}/C_{11}$ ) is defined as the ratio of the relative contraction strain normal to the applied force to the relative extension strain in the force direction. These two key factors are calculated and depicted in Fig. 3. In this figure, we show the dependence of  $Y_{2D}$ and  $\nu$  on the direction of three monolayers. The circular features of  $Y_{2D}$  and  $\nu$  in the polar diagram indicate the fully elastic isotropy of the CrXO monolayers. For comparison, the values of  $C_{ij}$ ,  $Y_{2D}$  and  $\nu$  are listed in Table 2. It is noticed that all the calculated elastic constants  $(C_{ij})$  are positive. It is demonstrated that all three monolayers obey the mechanical stability constraints, namely  $C_{11} > C_{12}$ ,  $C_{11} + 2C_{12} > 0$ , and  $C_{66} > 0.5^{2}$  We obtained the decreasing values of  $Y_{2D}$  in order of CrSO > CrSeO > CrTeO. This means monolayer CrTeO is the easiest one to deform under in-plane external force, followed by CrSeO and CrSO. It is reasonable and in good agreement with the previous



Fig. 3 Polar diagram for the Young's modulus (a) and Poisson's ratio (b) of CrXO monolayers (X = S, Se, Te).

Table 2Elastic constant  $C_{ij}$ , Young's modulus  $Y_{2D}$ , Poisson's ratio of<br/>the Janus CrXO monolayers (X = S, Se, Te)

	$C_{11} ({ m N m}^{-1})$	$C_{12} ({\rm N \ m}^{-1})$	$C_{66} ({ m N m}^{-1})$	$Y_{\rm 2D} \left( { m N m}^{-1}  ight)$	ν
CrSO	157.86	43.71	57.08	145.76	0.28
CrSeO	137.12	46.46	45.33	121.38	0.34
CrTeO	103.88	83.17	10.35	37.28	0.80

analysis in Section 1 since the Cr–Te bonds are the longest and deformable compared to those of Cr–Se and Cr–O. In contrast to the values of  $Y_{2D}$ , those of  $\nu$  are increasing from CrSO to CrTeO. Besides, the calculated Poisson's ratio values are all positive demonstrating the tendency of expansion (contraction) in the perpendicular direction when a compressive strain (tensile) is acted in one direction. One can use the  $\nu$  to evaluate the ductile–brittle behaviors.<sup>53</sup> Our calculated results indicate that CrSO monolayer is brittle with  $\nu < 0.31$ , while CrSeO and CrTeO monolayers with  $\nu > 0.31$  are ductile, where CrTeO is much more ductile with  $\nu = 0.80$  (about 80% higher compared to that of CrSeO). The obtained results for both Young's modulus ( $Y_{2D}$ ) and Poisson's ratio ( $\nu$ ) are in good accordance with each other.

#### 3.2 Electronic structures

After proving that the Janus CrXO monolayers studies here are dynamically stable, we use both PBE and HSE06 functionals in order to examine precisely the variation of electronic properties of all three systems and confirm our calculations. We calculate the electronic structure of these systems along the  $\Gamma$ -M-K- $\Gamma$ direction in the energy intervals -3 eV to 3 eV. Our calculations demonstrate that all three structures of CrXO are non-magnetic materials. Previously, CrO<sub>2</sub>, CrS<sub>2</sub>, CrSe<sub>2</sub> and CrTe<sub>2</sub> monolayers were reported to be non-magnetic semiconductors.39,40 The energy band structures plotted in Fig. 4 present the same profiles for three monolayers by both PBE and HSE06 functional. Unlike their binary counterparts, the Janus CrSeO and CrTeO monolayers become metallic at both PBE and HSE06 levels. Meanwhile, CrSO monolayer is low indirect semiconductor with bandgap of  $E_{\rm g}^{\rm PBE} = 0.22$  eV and  $E_{\rm g}^{\rm HSE06} =$ 0.72 eV at the PBE and HSE06 levels, respectively (Table 3), and its conduction band minimum (CBM) and valence band maximum (VBM) points reside at the K and  $\Gamma$  points at the equilibrium state. The significant enlargement (more than three times) of the calculated bandgap by HSE06 compared to PBE is observed and can be attributed to the underestimation the bandgap problem of semiconductors and insulators by PBE functional. To get a better insight into the electronic characteristics of the three materials, the weighted bands are also examined (Fig. 5). From the plotted weighted bands, it can be estimated the contributions of each atomic orbitals to the VBM/ CBM. It is found that both VBM and CBM of the band structures of CrSO are constituted due to Cr-d orbitals.

Due to the vertical asymmetry, there is an intrinsic built-in electric field available in the Janus structures.<sup>54</sup> Hence, there is a difference in vacuum levels between two different sides of the Janus structure. Therefore, the dipole correction<sup>55</sup> is used in the calculations for the electrostatic potential as shown in Fig. 6. Fermi level  $E_{\rm F}$ , vacuum level difference  $\Delta \Phi$ , and work functions  $\Phi_{\rm X}$  and  $\Phi_{\rm O}$  on two different sides of the Janus CrXO monolayers are calculated to evaluate the electron's ability to escape from the material surfaces (Table 3). Since the electronegativities of the X and O atoms are different, a finite out-ofplane dipole moment is appeared owing to the transfer of charges across the metal. The shifting in the vacuum level on the two sides of the monolayer observed in Fig. 6 can be used to evaluate the size of this dipole. It is worth noting that the vacuum level will be different due to the dipole-induced potential step. The Fermi levels shift up from -3.28 eV to -2.78 eV, and -1.44 eV with increasing the atomic number from S to Te, leading to the shifting of d-band away from the Fermi level, which also causes the most depletion in the band structure close to the Fermi level of CrTeO monolayer, followed by that of CrSeO monolayer. This can result in the transition to metallic properties of Janus CrSeO and CrTeO monolayers from the direct semiconducting natures of their counterparts, which is in good agreement with the electronic band structure observation. Due to the lacking of the vertical symmetry, the work functions  $\Phi_X$  and  $\Phi_O$  are different on two sides. For CrSO and CrSeO monolayers, the difference of work function on two sides,  $\Delta \Phi$ , are similar (about 2.5 eV) and 0.9 eV higher than that in CrTeO monolayer. This discrepancy could be due to the larger electronegativity of the S and Se atoms compare to that of Te.

It is well-known that the SOC effect plays an important in the electronic characteristics of 2D nanomaterials, especially



Fig. 4 Band structures of CrXO (X = S, Se, Te) monolayers at the PBE (solid lines) and HSE06 (dashed lines) levels.

**Table 3** Evaluated bandgaps  $E_g$  using the PBE, PBE+SOC, and HSE06 functionals, Fermi level  $E_F$ , vacuum level difference  $\Delta \Phi$ , and work functions  $\Phi_X$  and  $\Phi_O$  on two different sides of the Janus CrXO monolayers. M stands for metallic characteristic

	$E_{\rm g}^{\rm PBE}$ (eV)	$E_{\rm g}^{\rm PBE+SOC}$ (eV)	$E_{\rm g}^{\rm HSE06}$ (eV)	$E_{\rm F}$ (eV)	$\Delta \Phi (\mathrm{eV})$	$\Phi_1$ (eV)	$\Phi_2 (eV)$
CrSO	0.22	0.21	0.72	-3.28	2.53	7.07	4.54
CrSeO	М	М	М	-2.78	2.52	6.55	4.03
CrTeO	М	М	Μ	-1.44	1.60	5.22	3.62



compounds based on heavily elements. In the present study, we also calculate the band structures of CrXO monolayer by using the PBE+SOC method to evaluate the influence of the SOC effect on their electronic properties. The PBE+SOC band structures of CrXO monolayers are depicted in Fig. 7. Our calculated results demonstrate that there are band splitting in the band structures of CrXO when the SOC is included, especially in compounds containing heavy components such as CrSeO and CrTeO. The metallic properties of both CrSeO and CrTeO monolayers are preserved and the band gap of CrSO does not change when the SOC effect was taken into account. The unchanging band gap of CrSO monolayer can be explained that there is no too heavy elements in the CrSO compound.

#### 3.3 Optical properties

Insight into the optical properties of a compound is essential and significant for many applications and applied research. Due to the metallic characteristics of CrSeO and CrTeO



**Fig. 6** Planar average electrostatic potential of CrXO (X = S, Se, Te). The horizontal dashed line refers to the Fermi.  $\Delta \Phi$  is the vacuum level difference in the vacuum between two sides.



Fig. 7 Calculated band structures of CrXO monolayers by the PBE+SOC method.

#### Paper

monolayers, hence, we only investigate the optical properties of the Janus CrSO by focusing on the complex dielectric function  $\varepsilon(\omega)$  and the adsorption coefficient  $A(\omega)$ . The  $\varepsilon(\omega)$  is one of the crucial parameters of materials in optoelectronic and photovoltaic applications and is defined as  $\varepsilon(\omega) = \varepsilon_1(\omega) + i\varepsilon_2(\omega)$ , where  $\varepsilon_1(\omega)$  and  $\varepsilon_2(\omega)$  are the real and the imaginary parts of the complex dielectric function. The real part of dielectric function  $\varepsilon_1(\omega)$  can be calculated based on Kramers–Kronig relation<sup>56,57</sup> which represents the electronic polarization under the incident light and the imaginary part  $\varepsilon_2(\omega)$  could be obtained from the momentum matrix elements between the occupied and unoccupied wave functions and describes all the transitions from VB to CB:<sup>56,57</sup>

$$\varepsilon_{2}{}^{ij}(\omega) = \frac{4\pi^{2}e^{2}}{Vm^{2}\omega^{2}} \sum_{km'\sigma} \langle kn\sigma | p_{i} | kn'\sigma \rangle \langle kn'\sigma | p_{j} | kn\sigma \rangle$$
$$\times f_{kn}(1 - f_{kn'}) \delta(E_{kn'} - E_{kn} - \hbar\omega), \tag{1}$$

where *V* is the unit cell volume;  $\omega$  and *p* are the incoming photon angular frequency and momentum operator, respectively;  $|kn\sigma\rangle$  and  $f_{kn}$  stand for the crystal wave-function and Fermi distribution function, respectively; *e* and *m* are the elementary charge and electron mass, respectively. The summations refer to the first Brillouin zone wave vectors.

Fig. 8(a) illustrates the evaluated real part (blue line) and imaginary part (red line) of the complex  $\varepsilon(\omega)$  for the Janus CrSO monolayer as a function of incoming photon energy up to 12 eV. As depicted in Fig. 8(a),  $\varepsilon_1(\omega)$  increases with increasing photon energy at low energy regime, passing through a broad peak of about 3 eV. Besides, further increase in the energy of photons leads to a lowering value of  $\varepsilon_1(\omega)$ . The imaginary part is positive indicating that light can propagate in this range from 0 eV to 12 eV. The static dielectric constant  $\varepsilon_1(0)$  is found to be about 2.3 eV.

Based on the complex  $\varepsilon(\omega)$ , the absorption coefficient  $A(\omega)$  is computed for further analysis of the optical properties and can be defined as<sup>57,58</sup>

$$A(\omega) = \frac{\sqrt{2}\omega}{c} \left[ \sqrt{\varepsilon_1(\omega)^2 + \varepsilon_2(\omega)^2} - \varepsilon_1(\omega) \right]^{1/2},$$
(2)

where *c* refers to the light speed in vacuum.

From Fig. 8(b), we can see that the optical gap of the Janus CrSO monolayer is deduced to be about 0.7 eV. This optical gap agrees well with the previous bandgap by using HSE06



Fig. 8 Dielectric function (a) and absorption coefficient (b) of CrSO monolayer.

functional. The Janus CrSO monolayer has a wide absorption spectrum. It has good optical absorption in both the visible and ultraviolet regions. The first absorption peak is in the near-ultraviolet region, at 5.37 eV. CrSO has the strongest light absorption in the near-ultraviolet region and maximum absorbance up to  $5.26 \times 10^5$  cm<sup>-1</sup> at the incoming photon energy of 7.82 eV. With a wide absorption spectrum and high absorption coefficient, CrSO can be a potential material for applications in optoelectronics.

## 4 Conclusion

In conclusion, we systematically considered the structural, mechanical, electronic, and optical properties of the 2D Janus CrXO monolayers by means of first-principles study. These three systems are constructed from 2H-phases counterparts Cr dichalcogenides or oxide. The optimized geometry configurations are obtained. The mechanical stabilities of Janus CrXO monolayers are demonstrated by phonon spectrum analysis in which the shift to lower frequencies are found for both optical and acoustic branches of three Janus monolayers. The stability of the Janus CrXO monolayers is verified by the satisfaction of the criteria for mechanical stability. The electronic structure analysis indicates that while the CrSeO and CrTeO monolayers are metallic, the CrSO monolayer is a low indirect semiconductor, at both PBE and HSE06 levels. We demonstrate the shift of metal d-band determines the electronic character of metal or semiconductor. Subsequently, the CrSO semiconductor has absorption in the visible and ultraviolet regions. Our results revealed the Janus CrXO (X = S, Se, Te) monolayers possess good properties that are potential candidates for optoelectronics and energy conversion applications.

## Conflicts of interest

There are no conflicts to declare.

#### References

- 1 K. S. Novoselov, A. K. Geim, S. V. Morozov, D. Jiang, Y. Zhang, S. V. Dubonos, I. V. Grigorieva and A. A. Firsov, *Science*, 2004, **306**, 666.
- 2 T. Cheng, H. Lang, Z. Li, Z. Liu and Z. Liu, *Phys. Chem. Chem. Phys.*, 2017, **19**, 23942–23950.
- 3 N. N. Hieu, H. V. Phuc, V. V. Ilyasov, N. D. Chien, N. A. Poklonski, N. V. Hieu and C. V. Nguyen, *J. Appl. Phys.*, 2017, 122, 104301.
- 4 H. T. T. Nguyen, M. M. Obeid, A. Bafekry, M. Idrees, T. V. Vu, H. V. Phuc, N. N. Hieu, L. T. Hoa, B. Amin and C. V. Nguyen, *Phys. Rev. B*, 2020, **102**, 075414.
- 5 H. Li, Y. Qin, B. Ko, D. B. Trivedi, D. Hajra, M. Y. Sayyad, L. Liu, S.-H. Shim, H. Zhuang and S. Tongay, *Adv. Mater.*, 2020, **32**, 2002401.
- 6 L. Zhang, Z. Yang, T. Gong, R. Pan, H. Wang, Z. Guo, H. Zhang and X. Fu, *J. Mater. Chem. A*, 2020, 8, 8813–8830.

8

- 7 E. Kovalska, J. Luxa, T. Hartman, N. Antonatos, P. Shaban, E. Oparin, M. Zhukova and Z. Sofer, *Nanoscale*, 2020, 12, 2638–2647.
- 8 M. Mahdavifar, S. Shekarforoush and F. Khoeini, *J. Phys. D: Appl. Phys.*, 2020, 54, 095108.
- 9 F.-f. Zhu, W.-j. Chen, Y. Xu, C.-l. Gao, D.-d. Guan, C.-h. Liu, D. Qian, S.-C. Zhang and J.-f. Jia, *Nat. Mater.*, 2015, 14, 1020–1025.
- B. J. Ryan, M. P. Hanrahan, Y. Wang, U. Ramesh, C. K. A. Nyamekye, R. D. Nelson, Z. Liu, C. Huang, B. Whitehead, J. Wang, L. T. Roling, E. A. Smith, A. J. Rossini and M. G. Panthani, *Chem. Mater.*, 2020, 32, 795–804.
- A. Acun, L. Zhang, P. Bampoulis, M. Farmanbar, A. van Houselt, A. N. Rudenko, M. Lingenfelder, G. Brocks, B. Poelsema, M. I. Katsnelson and H. J. W. Zandvliet, *J. Phys.: Condens. Matter*, 2015, 27, 443002.
- 12 R. Chegel and S. Behzad, Sci. Rep., 2020, 10, 704.
- 13 J.-H. Park, X. Yang, J.-Y. Lee, M.-D. Park, S.-Y. Bae, M. Pristovsek, H. Amano and D.-S. Lee, *Chem. Sci.*, 2021, 12, 7713–7719.
- 14 A. T. Hoang, K. Qu, X. Chen and J.-H. Ahn, *Nanoscale*, 2021, 13, 615–633.
- 15 Z. Hu, Z. Wu, C. Han, J. He, Z. Ni and W. Chen, *Chem. Soc. Rev.*, 2018, **47**, 3100–3128.
- 16 N. D. Hien, C. V. Nguyen, N. N. Hieu, S. S. Kubakaddi, C. A. Duque, M. E. Mora-Ramos, L. Dinh, T. N. Bich and H. V. Phuc, *Phys. Rev. B*, 2020, **101**, 045424.
- 17 D. Muoi, N. N. Hieu, C. V. Nguyen, B. D. Hoi, H. V. Nguyen, N. D. Hien, N. A. Poklonski, S. S. Kubakaddi and H. V. Phuc, *Phys. Rev. B*, 2020, **101**, 205408.
- 18 T. V. Vu, C. V. Nguyen, H. V. Phuc, A. A. Lavrentyev, O. Y. Khyzhun, N. V. Hieu, M. M. Obeid, D. P. Rai, H. D. Tong and N. N. Hieu, *Phys. Rev. B*, 2021, **103**, 085422.
- 19 H. T. T. Nguyen, L. Dinh, T. V. Vu, L. T. Hoa, N. N. Hieu, C. V. Nguyen, H. V. Nguyen, S. S. Kubakaddi and H. V. Phuc, *Phys. Rev. B*, 2021, **104**, 075445.
- 20 T. N. Bich, S. S. Kubakaddi, L. Dinh, N. N. Hieu and H. V. Phuc, *Phys. Rev. B*, 2021, **103**, 235417.
- 21 K. Ren, C. Ren, Y. Luo, Y. Xu, J. Yu, W. Tang and M. Sun, *Phys. Chem. Chem. Phys.*, 2019, 21, 9949–9956.
- 22 W. Feng, G.-Y. Guo and Y. Yao, 2D Mater., 2016, 4, 015017.
- 23 X. Huang, Z. Zeng and H. Zhang, *Chem. Soc. Rev.*, 2013, 42, 1934–1946.
- 24 A. A. Bukharaev, A. K. Zvezdin, A. P. Pyatakov and Y. K. Fetisov, *Phys.-Usp.*, 2018, **61**, 1175–1212.
- 25 H. T. T. Nguyen, V. V. Tuan, C. V. Nguyen, H. V. Phuc,
  H. D. Tong, S.-T. Nguyen and N. N. Hieu, *Phys. Chem. Chem. Phys.*, 2020, 22, 11637–11643.
- 26 Y. Cui, L. Peng, L. Sun, M. Li, X. Zhang and Y. Huang, J. Phys.: Condens. Matter, 2020, 32, 08LT01.
- 27 T. V. Vu, V. T. T. Vi, H. V. Phuc, A. I. Kartamyshev and N. N. Hieu, *Phys. Rev. B*, 2021, **104**, 115410.
- 28 M. Yagmurcukardes and F. M. Peeters, *Phys. Rev. B*, 2020, **101**, 155205.
- 29 I. Ahmad, I. Shahid, A. Ali, L. Gao and J. Cai, *RSC Adv.*, 2021, **11**, 17230.

- 30 L. Dong, J. Lou and V. B. Shenoy, *ACS Nano*, 2017, **11**, 8242–8248.
- 31 N. N. Som and P. K. Jha, Int. J. Hydrogen Energy, 2019, 45, 23920-23927.
- 32 W.-L. Tao, Y. Mu, C.-E. Hu, Y. Cheng and G.-F. Ji, *Philos. Mag.*, 2019, **99**, 1025.
- 33 J. Zhou, Q. Wang, Q. Sun, X. S. Chen, Y. Kawazoe and P. Jena, *Nano Lett.*, 2009, 9, 3867–3870.
- 34 A.-Y. Lu, H. Zhu, J. Xiao, C.-P. Chuu, Y. Han, M.-H. Chiu, C.-C. Cheng, C.-W. Yang, K.-H. Wei, Y. Yang, Y. Wang, D. Sokaras, D. Nordlund, P. Yang, D. A. Muller, M.-Y. Chou, X. Zhang and L.-J. Li, *Nat. Nanotechnol.*, 2017, 12, 744.
- 35 J. Zhang, S. Jia, I. Kholmanov, L. Dong, D. Er, W. Chen, H. Guo, Z. Jin, V. B. Shenoy, L. Shi and J. Lou, *ACS Nano*, 2017, **11**, 8192–8198.
- 36 Y. Qu, H. Pan and C. T. Kwok, Sci. Rep., 2016, 6, 34186.
- 37 S. Das, J. A. Robinson, M. Dubey, H. Terrones and M. Terrones, Annu. Rev. Mater. Res., 2015, 45, 1–27.
- 38 C. M. O. Bastos, R. Besse, J. L. F. Da Silva and G. M. Sipahi, *Phys. Rev. Mater.*, 2019, **3**, 044002.
- 39 C. Ataca, H. Şahin and S. Ciraci, *J. Phys. Chem. C*, 2012, **116**, 8983–8999.
- 40 F. A. Rasmussen and K. S. Thygesen, *J. Phys. Chem. C*, 2015, **119**, 13169.
- 41 D. Çakır, F. M. Peeters and C. Sevik, *Appl. Phys. Lett.*, 2014, **104**, 203110.
- 42 P. Giannozzi, S. Baroni, N. Bonini, M. Calandra, R. Car, C. Cavazzoni, D. Ceresoli, G. L. Chiarotti, M. Cococcioni, I. Dabo, A. D. Corso, S. de Gironcoli, S. Fabris, G. Fratesi, R. Gebauer, U. Gerstmann, C. Gougoussis, A. Kokalj, M. Lazzeri, L. Martin-Samos, N. Marzari, F. Mauri, R. Mazzarello, S. Paolini, A. Pasquarello, L. Paulatto, C. Sbraccia, S. Scandolo, G. Sclauzero, A. P. Seitsonen, A. Smogunov, P. Umari and R. M. Wentzcovitch, *J. Phys.: Condens. Matter*, 2009, 21, 395502.
- 43 G. Kresse and D. Joubert, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1999, **59**, 1758.
- 44 A. H. MacDonald, W. E. Picket and D. D. Koelling, J. Phys. C: Solid State Phys., 1980, 13, 2675.
- 45 J. Heyd, G. E. Scuseria and M. Ernzerhof, *J. Chem. Phys.*, 2003, **118**, 8207.
- 46 S. Grimme, J. Comput. Chem., 2006, 27, 1787.
- 47 T. Sohier, M. Calandra and F. Mauri, *Phys. Rev. B*, 2017, **96**, 075448.
- 48 P. D. Borges, L. M. Scolfaro, H. W. Leite Alves, E. F. da Silva and L. V. Assali, *Nanoscale Res. Lett.*, 2011, 6, 146.
- 49 H. Y. Lv, W. J. Lu, D. F. Shao, Y. Liu and Y. P. Sun, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2015, **92**, 214419.
- 50 F. T. Bölle, A. E. G. Mikkelsen, K. S. Thygesen, T. Vegge and I. E. Castelli, *npj Comput. Mater.*, 2021, 7, 41.
- 51 L. Pauling, Proc. Natl. Acad. Sci. U. S. A., 1930, 16, 578-582.
- 52 F. Mouhat and F.-X. Coudert, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2014, **90**, 224104.
- 53 D. G. Pettifor, Mater. Sci. Technol., 1992, 8, 345.
- 54 C.-F. Fu, J. Sun, Q. Luo, X. Li, W. Hu and J. Yang, *Nano Lett.*, 2018, **18**, 6312–6317.

#### Paper

- 55 L. Bengtsson, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1999, **59**, 12301.
- 56 A. Delin, P. Ravindran, O. Eriksson and J. Wills, Int. J. Quantum Chem., 1998, 69, 349.
- 57 S. Z. Karazhanov, P. Ravindran, A. Kjekshus, H. Fjellvag and B. G. Svensson, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 2007, 75, 155104.
- 58 P. Ravindran, A. Delin, B. Johansson, O. Eriksson and J. M. Wills, *Phys. Rev. B: Condens. Matter Mater. Phys.*, 1999, **59**, 1776–1785.